

February 1988

MM54C08/MM74C08 Quad 2-Input AND Gate

General Description

Employing complementary MOS (CMOS) transistors to achieve wide power supply operating range, low power consumption and high noise margin, these gates provide basic functions used in the implementation of digital integrated circuit systems. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swing essentially equal to the supply voltage. No DC power other than that caused by leakage current is consumed during static condition. All inputs are protected from damage due to static discharge by diode clamps to V_{CC} and GND.

Features

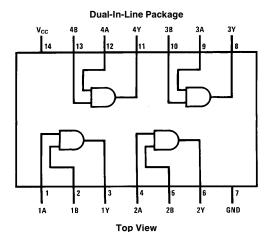
- Wide supply voltage range
- Guaranteed noise margin
- High noise immunity
- Low power TTL compatibility
- Low power consumption

3.0V to 15V 1.0V

0.45 V_{CC} (typ.) Fan out of 2 driving 74L

10 nW/package (typ.)

Connection Diagram and Truth Table



TL/F/5878-1

Order Number MM54C08 or MM74C08

Inputs		Outputs		
Α	В	Υ		
L	L	L		
L	Н	L		
Н	L	L		
Н	Н	Н		

H = High Level L = Low Level

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at Any Pin

-0.3 V to $V_{\hbox{\footnotesize CC}}\,+\,0.3 V$

Operating Temperature Range MM54C08 MM74C08

-55°C to +125°C -40°C to +85°C Storage Temperature Range

Power Dissipation (P_D) Dual-In-Line

700 mW 500 mW

 -65°C to $+\,150^{\circ}\text{C}$

3.0V to 15V 18V

Lead Temperature (Soldering, 10 seconds)

260°C

DC Electrical Characteristics

Min/Max limits apply across the guaranteed temperature range, unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO	CMOS					
V _{IN(1)} Logical "1" Input Vol	Logical "1" Input Voltage	V _{CC} = 5.0V	3.5			V
		V _{CC} = 10V	8.0			V
V _{IN(0)} Logical "	Logical "0" Input Voltage	V _{CC} = 5.0V			1.5	V
		V _{CC} = 10V			2.0	V
V _{OUT(1)} Logical "1" Out	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} = -10 \mu A$	4.5			V
		$V_{CC} = 10V, I_{O} = -10 \mu A$	9.0			V
V _{OUT(0)} Logical "0"	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_{O} = 10 \mu A$			0.5	V
		$V_{CC} = 10V, I_{O} = 10 \mu A$			1.0	٧
I _{IN(1)}	Logical "1" Input Current	$V_{CC} = 15V, V_{IN} = 15V$		0.005	1.0	μΑ
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		μΑ
Icc	Supply Current	V _{CC} = 15V		0.01	15	μΑ
CMOS/LP	TTL INTERFACE		•	1		
V _{IN(1)} Logical "1"	Logical "1" Input Voltage	54C, V _{CC} = 4.5V	V _{CC} - 1.5			V
		74C, V _{CC} = 4.75V	V _{CC} - 1.5			٧
V _{IN(0)} Logical "0" Input Volta	Logical "0" Input Voltage	54C, V _{CC} = 4.5V			0.8	٧
		74C, V _{CC} = 4.75V			0.8	٧
V _{OUT(1)} Logical "1" Output	Logical "1" Output Voltage	54C, $V_{CC} = 4.5V$, $I_{O} = -360 \mu A$	2.4			٧
		74C, $V_{CC} = 4.75V$, $I_{O} = -360 \mu\text{A}$	2.4			٧
V _{OUT(0)} Logi	Logical "0" Output Voltage	54C, $V_{CC} = 4.5V$, $I_O = 360 \mu A$			0.4	V
		74C, $V_{CC} = 4.75V$, $I_{O} = 360 \mu A$			0.4	V
OUTPUT D	PRIVE (see 54C/74C Family Ch	aracteristics Data Sheet) T _A = 25°C (short circuit cu	rrent)		
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 5.0V, V_{OUT} = 0V$	-1.75	-3.3		mA
ISOURCE	Output Source Current (P-Channel)	$V_{CC} = 10V, V_{OUT} = 0V$	-8.0	15		mA
I _{SINK}	Output Sink Current (N-Channel)	$V_{CC} = 5.0V, V_{OUT} = V_{CC}$	1.75	3.6		mA
ISINK	Output Sink Current (N-Channel)	$V_{CC} = 10V, V_{OUT} = V_{CC}$	8.0	16		mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

AC Electrical Characteristics* (MM54C08/MM74C08) $T_A = 25^{\circ}\text{C}$, $C_L = 50$ pF, unless otherwise specified

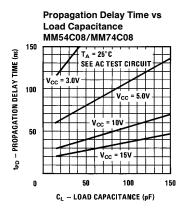
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{pd0} , t _{pd1}	Propagation Delay Time to Logical "1" or "0"	$V_{CC} = 5.0V$		80	140	ns
		$V_{CC} = 10V$		40	70	ns
C _{IN}	Input Capacitance	(Note 2)		5.0		pF
C _{PD}	Power Dissipation Capacitance	(Note 3) Per Gate		14		pF

^{*}AC Parameters are guaranteed by DC correlated testing.

Note 2: Capacitance is guaranteed by periodic testing.

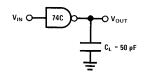
Note 3: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application Note—AN-90.

Typical Performance Characteristics



TL/F/5878-2

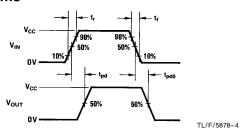
AC Test Circuit



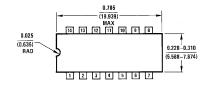
TL/F/5878-3

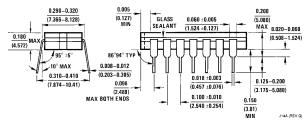
Note: Delays measured with input $t_{\rm f},\,t_{\rm f}=$ 20 ns

Switching Time Waveforms

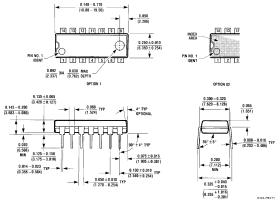


Physical Dimensions inches (millimeters)





Ceramic Dual-In-Line Package (J)
Order Number MM54C08J or MM74C08J
NS Package Number J14A



Molded Dual-In-Line Package (N)
Order Number MM54C08N or MM74C08N
NS Package Number N14A

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